REF3212, REF3220 REF3225. REF3230

REF3225, REF3230 REF3233, REF3240

SBVS058C -JUNE 2005-REVISED AUGUST 2011

4ppm/°C, 100µA, SOT23-6 SERIES VOLTAGE REFERENCE

Check for Samples: REF3212, REF3220, REF3225, REF3230, REF3233, REF3240

FEATURES

www.ti.com

• Excellent Specified Drift Performance:

7ppm/°C (max) at 0°C to +125°C

20ppm/°C (max) at -40°C to +125°C

Microsize Package: SOT23-6High Output Current: ±10mA

High Accuracy: 0.01%

Low Quiescent Current: 100µA

Low Dropout: 5mV

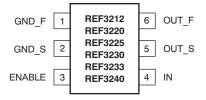
APPLICATIONS

Portable Equipment

· Data Acquisition Systems

Medical Equipment

Test Equipment



DESCRIPTION

The REF32xx is a very low drift, micropower, low-dropout, precision voltage reference family available in the tiny SOT23-6 package.

The small size and low power consumption ($120\mu A$ max) of the REF32xx make it ideal for portable and battery-powered applications. This reference is stable with any capacitive load.

The REF32xx can be operated from a supply as low as 5mV above the output voltage, under no load conditions. All models are specified for the wide temperature range of -40°C to $+125^{\circ}\text{C}$.

AVAILABLE OUTPUT VOLTAGES

PRODUCT	VOLTAGE
REF3212	1.25V
REF3220	2.048V
REF3225	2.5V
REF3230	3.0V
REF3233	3.3V
REF3240	4.096

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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGE INFORMATION(1)

PRODUCT	OUTPUT VOLTAGE	PACKAGE-LEAD	PACKAGE DESIGNATOR	PACKAGE MARKING
REF3212	1.25V	SOT23-6	DBV	R32A
REF3220	2.048V	SOT23-6	DBV	R32B
REF3225	2.5V	SOT23-6	DBV	R32C
REF3230	3.0V	SOT23-6	DBV	R32D
REF3233	3.3V	SOT23-6	DBV	R32E
REF3240	4.096	SOT23-6	DBV	R32F

⁽¹⁾ For the most current package and ordering information see the Package Option Addendum at the end of this document, or visit the device product folder at www.ti.com.

ABSOLUTE MAXIMUM RATINGS(1)

Over operating free-air temperature range (unless otherwise noted).

		REF32xx	UNIT
Input voltage		+7.5	V
Output short-circuit		Continuous	
Operating temp	erature	−55 to +135	°C
Storage temper	ature	-65 to +150	°C
Junction temper	rature	+150	°C
	Human body model (HBM)	4	kV
ESD ratings	Charged device model (CDM)	1	kV
	Machine model (MM)	400	V

⁽¹⁾ Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

PIN CONFIGURATION

DBV PACKAGE

SOT23-6 (TOP VIEW) GND_F 1 6 OUT_F GND_S 2 5 OUT_S ENABLE 3 4 IN

NOTE:: The location of pin 1 on the REF32xx is determined by orienting the package marking as shown in the diagram above.

PIN DESCRIPTIONS

PIN			
NAME	NO.	FUNCTION	DESCRIPTION
ENABLE	3	Digital input	This pin enables and disables the device
GND_F	1	Analog output	Ground connection of the device
GND_S	2	Analog input	Ground sense at the load
IN	4	Analog input	Positive supply voltage
OUT_F	6	Analog output	Output of Reference Voltage
OUT_S	5	Analog input	Sense connection at the load





ELECTRICAL CHARACTERISTICS

Boldface limits apply over the listed temperature range.

At $T_A = +25$ °C, $I_{LOAD} = 0$ mA, and $V_{IN} = 5$ V, unless otherwise noted.

		REF32xx			
PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
	REF3212 (1.25V)				
OUTPUT VOLTAGE, V _{OUT}		1.2475	1.25	1.2525	V
Initial accuracy		-0.2	0.01	0.2	%
NOISE					
Output voltage noise	f = 0.1Hz to 10Hz		17		μV_{PP}
Voltage noise	f = 10Hz to 10kHz		24		μV_{RMS}
	REF3220 (2.048V)				
OUTPUT VOLTAGE, V _{OUT}		2.044	2.048	2.052	V
Initial accuracy		-0.2	0.01	0.2	%
NOISE					
Output voltage noise	f = 0.1Hz to 10Hz		27		μV_{PP}
Voltage noise	f = 10Hz to 10kHz		39		μV_{RMS}
	REF3225 (2.5V)			,	
OUTPUT VOLTAGE, V _{OUT}		2.495	2.50	2.505	V
Initial accuracy		-0.2	0.01	0.2	%
NOISE					
Output voltage noise	f = 0.1Hz to 10Hz		33		μV_{PP}
Voltage noise	f = 10Hz to 10kHz		48		μV_{RMS}
	REF3230 (3V)	1			
OUTPUT VOLTAGE, V _{OUT}		2.994	3	3.006	V
Initial accuracy		-0.2	0.01	0.2	%
NOISE					
Output voltage noise	f = 0.1Hz to 10Hz		39		μV_{PP}
Voltage noise	f = 10Hz to 10kHz		57		μV_{RMS}
	REF3233 (3.3V)				
OUTPUT VOLTAGE, V _{OUT}		3.293	3.3	3.307	V
Initial accuracy		-0.2	0.01	0.2	%
NOISE					
Output voltage noise	f = 0.1Hz to 10Hz		43		μV_{PP}
Voltage noise	f = 10Hz to 10kHz		63		μV_{RMS}
	REF3240 (4.096V)	1			
OUTPUT VOLTAGE, V _{OUT}		4.088	4.096	4.104	V
Initial accuracy		-0.2	0.01	0.2	%
NOISE					
Output voltage noise	f = 0.1Hz to 10Hz		53		μV_{PP}
Voltage noise	f = 10Hz to 10kHz		78		μV_{RMS}



ELECTRICAL CHARACTERISTICS (continued)

Boldface limits apply over the listed temperature range.

At $T_A = +25$ °C, $I_{LOAD} = 0$ mA, and $V_{IN} = 5$ V, unless otherwise noted.

			R				
PARAMETER		CONDITIONS	MIN	TYP	MAX	UNIT	
	REF32	212 / REF3220 / REF3225 / REF3230 / REF3233 /	REF3240				
OUTPUT VOLTAGE TEMP DRIFT	dV _{OUT} /dT						
		$0^{\circ}C \leq T_{A} \leq +125^{\circ}C$		4	7	ppm/°C	
		-40° C \leq T _A \leq +125 $^{\circ}$ C		10.5	20	ppm/°C	
LONG-TERM STABILITY		0 to 1000h		55		ppm	
LINE REGULATION		$V_{OUT} + 0.05^{(1)} \le V_{IN} \le 5.5V$	-65	15	+65	ppm/V	
LOAD REGULATION ⁽²⁾	dV _{OUT} /dI _{LOAD}						
Sourcing		$0mA < I_{LOAD} < 10mA, V_{IN} = V_{OUT} + 250mV^{(1)}$	-40	3	40	μV/mA	
Sinking		$-10\text{mA} < I_{LOAD} < 0\text{mA}, V_{IN} = V_{OUT} + 100\text{mV}^{(1)}$	-60	20	60	μV/mA	
THERMAL HYSTERESIS (3)	dT						
First cycle				100		ppm	
Additional cycles				25		ppm	
DROPOUT VOLTAGE ⁽¹⁾	$V_{IN} - V_{OUT}$	0°C ≤ T _A ≤ +125°C		5	50	mV	
OUTPUT CURRENT	I _{LOAD}	$V_{IN} = V_{OUT} + 250 \text{mV}^{(1)}$	-10		10	mA	
SHORT-CIRCUIT CURRENT	I _{sc}						
Sourcing				50		mA	
Sinking				40		mA	
TURN-ON SETTLING TIME		To 0.1% at $V_{IN} = 5V$ with $C_L = 0$		60		μs	
ENABLE/SHUTDOWN ⁽⁴⁾							
	V_L	Reference in Shutdown mode	0		0.7	V	
	V_{H}	Reference is active	1.5		V_{IN}	V	
POWER SUPPLY		I _L = 0					
Voltage	V_{IN}		V _{OUT} + 0.05 ⁽¹⁾		5.5	V	
Current	I_Q	ENABLE > 1.5V		100	120	μΑ	
Over temperature		$0^{\circ}C \leq T_{A} \leq +125^{\circ}C$		115	135	μΑ	
Shutdown	I _S	ENABLE < 0.7V		0.1	1	μΑ	
TEMPERATURE RANGE							
Specified			-40		+125	°C	
Operating			-55		+135	°C	
Storage			-65		+150	°C	
Thermal resistance, SOT23-6	θ_{JA}			200		°C/W	

The minimum supply voltage for the REF3212 is 1.8V.

Load regulation is using force and sense lines; see the *Load Regulation* section for more information. Thermal hysteresis procedure is explained in more detail in the Applications Information TBD section.

If the rise time of the input voltage is less than or equal to 2ms, the ENABLE and IN pins can be tied together. For rise times greater than 2ms, see the *Supply Voltage* section.



TYPICAL CHARACTERISTICS

At $T_A = +25$ °C, $I_{LOAD} = 0$ mA, $V_{IN} = +5$ V power supply, and REF3225 used for typical characteristics, unless otherwise noted.

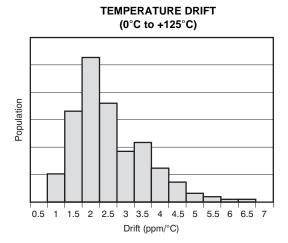


Figure 1.

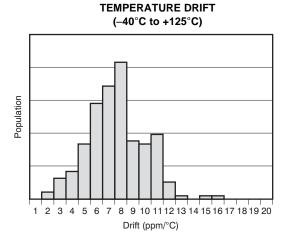


Figure 2.

OUTPUT VOLTAGE ACCURACY vs TEMPERATURE

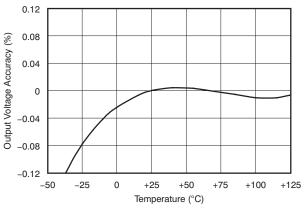


Figure 3.

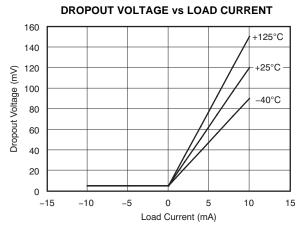


Figure 4.

QUIESCENT CURRENT vs TEMPERATURE

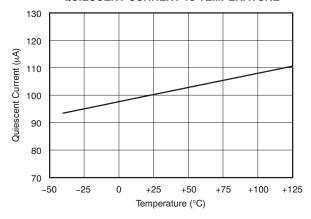


Figure 5.

POWER-SUPPLY REJECTION RATIO vs FREQUENCY

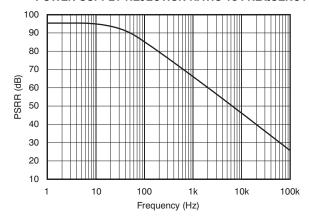


Figure 6.



TYPICAL CHARACTERISTICS (continued)

At $T_A = +25$ °C, $I_{LOAD} = 0$ mA, $V_{IN} = +5$ V power supply, and REF3225 used for typical characteristics, unless otherwise noted.

OUTPUT VOLTAGE vs INPUT VOLTAGE (REF3212)

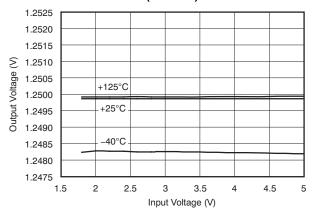


Figure 7.

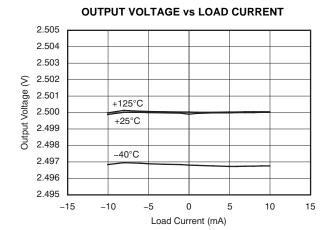


Figure 8.

0.1Hz TO 10Hz NOISE

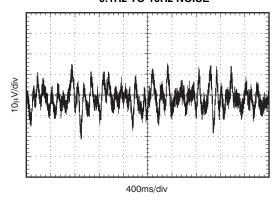


Figure 9.

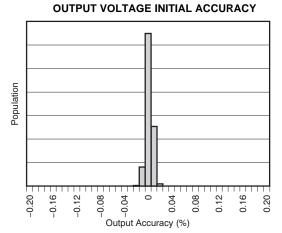


Figure 10.

STEP RESPONSE $C_L = 0pF, 5V STARTUP$

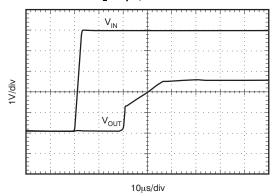


Figure 11.

STEP RESPONSE $C_L = 1\mu F$

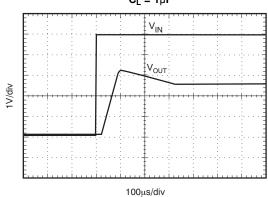


Figure 12.



TYPICAL CHARACTERISTICS (continued)

At $T_A = +25$ °C, $I_{LOAD} = 0$ mA, $V_{IN} = +5$ V power supply, and REF3225 used for typical characteristics, unless otherwise noted.

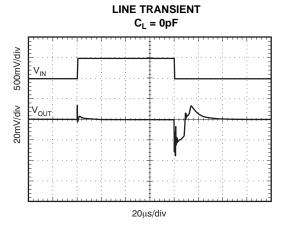


Figure 13.

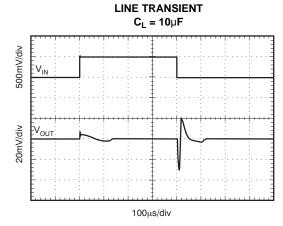
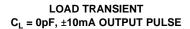


Figure 14.



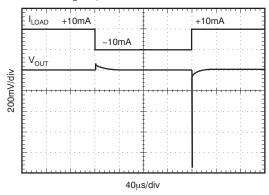


Figure 15.

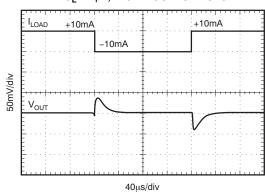


Figure 16.

LOAD TRANSIENT $C_L = 0$ pF, ± 1 mA OUTPUT PULSE

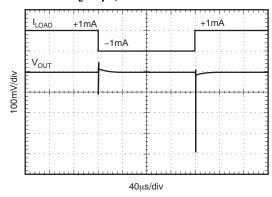


Figure 17.

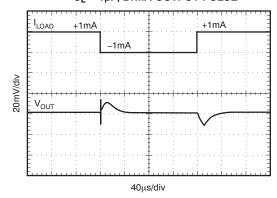
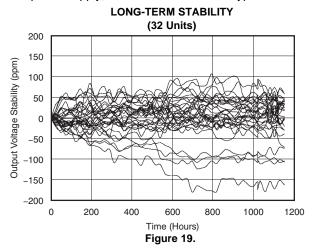


Figure 18.

TYPICAL CHARACTERISTICS (continued)

At $T_A = +25$ °C, $I_{LOAD} = 0$ mA, $V_{IN} = +5$ V power supply, and REF3225 used for typical characteristics, unless otherwise noted.



THEORY OF OPERATION

GENERAL DESCRIPTION

The REF32xx is a family of CMOS, precision bandgap voltage references. Figure 20 shows the basic bandgap topology. Transistors Q_1 and Q_2 are biased so that the current density of Q_1 is greater than that of Q_2 . The difference of the two base-emitter voltages (Vbe $_1$ – Vbe $_2$) has a positive temperature coefficient and is forced across resistor R_1 . This voltage is amplified and added to the base-emitter voltage of Q_2 , which has a negative temperature coefficient. The resulting output voltage is virtually independent of temperature.

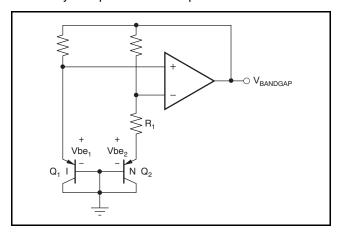


Figure 20. Simplified Schematic of Bandgap Reference

APPLICATION INFORMATION

The REF32xx does not require a load capacitor and is stable with any capacitive load. Figure 21 shows typical connections required for operation of the REF32xx. A supply bypass capacitor of 0.47µF is recommended.

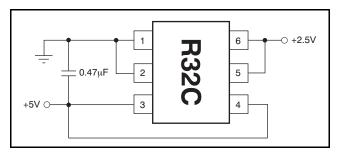


Figure 21. Typical Operating Connections for the RFF3225

SUPPLY VOLTAGE

The REF32xx family of references features an extremely low dropout voltage. With the exception of the REF3212, which has a minimum supply requirement of 1.8V, these references can be operated with a supply of only 5mV above the output voltage in an unloaded condition. For loaded conditions, a typical dropout voltage versus load is shown in the Typical Characteristic curves.



The REF32xx also features a low quiescent current of $100\mu A$, with a maximum quiescent current over temperature of just $135\mu A$. The quiescent current typically changes less than $2\mu A$ over the entire supply range, as shown in Figure 22.

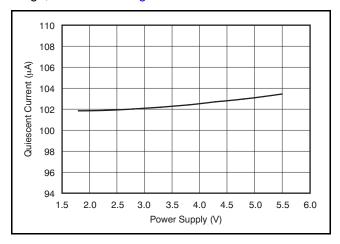


Figure 22. Supply Current vs Supply Voltage

Supply voltages below the specified levels can cause the REF32xx to momentarily draw currents greater than the typical quiescent current. This momentary current draw can be prevented by using a power supply with a fast rising edge and low output impedance.

For optimal startup when the IN pin and ENABLE pin are tied together, keep the input voltage rise time less than or equal to 2ms. For rise times greater than 2ms, the ENABLE pin must be kept below 0.7V until the voltage at the IN pin has reached the minimum operating voltage. One way to control the voltage at the ENABLE pin is with an additional RC filter, such as that shown in Figure 23. The RC filter must hold the voltage at the ENABLE pin below the threshold voltage until the voltage at the input pin has reached the minimum operating voltage.

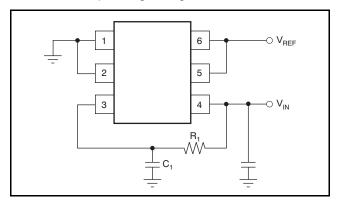


Figure 23. Application Circuit to Control the REF32xx ENABLE Pin

The RC filter in Figure 23 can be used as a starting point for the REF3240. The values for R_1 and C_1 have been calculated so that the voltage at the ENABLE pin reaches 0.7V after the input voltage has reached 4.15V; Table 1 lists these values. For output voltage options other than 4.096V, the RC filter can be made faster.

Table 1. Recommended R₁ and C₁ Values for the REF3240

RISE TIME	R ₁ VALUE	C ₁ VALUE
2ms	150kΩ	100nF
5ms	150kΩ	220nF
10ms	330kΩ	220nF
20ms	390kΩ	330nF
50ms	680kΩ	470nF
100ms	680kΩ	1000nF

In this document, rise time is defined as the time until an exponential input signal reaches 90% of its final voltage. For example, the 2ms value shown in Table 1 is valid for an end value of 5V.

If the input voltage has a different shape or the end value is not 5V, then the time until the minimum dropout voltage has been reached should be used to decide if the IN and ENABLE pins can be tied together. Table 2 lists these times.

Table 2. Minimum Dropout Voltage Times

DEVICE	TIME
REF3212	0.4ms
REF3220	0.5ms
REF3225	0.7ms
REF3230	0.9ms
REF3233	1.0ms
REF3240	1.6ms

Note that because the leakage current of the EN pin is in the range of a few nA, it can be disregarded in most applications.

SHUTDOWN

The REF32xx can be placed in a low-power mode by pulling the ENABLE/SHUTDOWN pin low. When in Shutdown mode, the output of the REF32xx becomes a resistive load to ground. The value of the load depends on the model, and ranges from approximately $100k\Omega$ to $400k\Omega.$



THERMAL HYSTERESIS

Thermal hysteresis for the REF32xx is defined as the change in output voltage after operating the device at +25°C, cycling the device through the specified temperature range, and returning to +25°C. It can be expressed as:

$$V_{HYST} = \left(\frac{V_{PRE} - V_{POST}}{V_{NOM}}\right) \times 10^{6} (ppm)$$

Where:

 V_{HYST} = thermal hysteresis (in units of ppm).

 V_{NOM} = the specified output voltage.

V_{PRE} = output voltage measured at +25°C pretemperature cycling.

V_{POST} = output voltage measured after the device has been cycled through the specified temperature range of -40°C to +125°C and returned to +25°C. (1)

TEMPERATURE DRIFT

The REF32xx is designed to exhibit minimal drift error, which is defined as the change in output voltage over varying temperature. The drift is calculated using the box method, as described by Equation 2:

Drift =
$$\left(\frac{V_{OUTMAX} - V_{OUTMIN}}{V_{OUT} \times \text{Temp Range}}\right) \times 10^6 \text{(ppm)}$$
 (2)

The REF32xx features a typical drift coefficient of 4ppm/°C from 0°C to +125°C—the primary temperature range for many applications. For the extended industrial temperature range of -40°C to +125°C, the REF32xx family drift increases to a typical value of 10.5ppm/°C.

NOISE PERFORMANCE

Typical 0.1Hz to 10Hz voltage noise can be seen in the Typical Characteristic curve, 0.1Hz to 10Hz Voltage Noise. The noise voltage of the REF32xx increases with output voltage and operating temperature. Additional filtering can be used to improve output noise levels, although care should be taken to ensure the output impedance does not degrade AC performance.

LONG-TERM STABILITY

Long-term stability refers to the change of the output voltage of a reference over a period of months or years. This effect lessens as time progresses, as is shown by the long-term stability Typical Characteristic curves. The typical drift value for the REF32xx is 55ppm from 0 to 1000 hours. This parameter is characterized by measuring 30 units at regular intervals for a period of 1000 hours.

LOAD REGULATION

Load regulation is defined as the change in output voltage as a result of changes in load current. The load regulation of the REF32xx is measured using force and sense contacts, as shown in Figure 24.

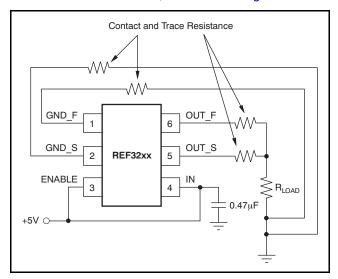


Figure 24. Accurate Load Regulation of REF32xx

The force and sense lines can be used to effectively eliminate the impact of contact and trace resistance, resulting in accurate voltage at the load. By connecting the force and sense lines at the load, the REF32xx compensates for the contact and trace resistances because it measures and adjusts the voltage actually delivered at the load.

The GND_S pin is connected to the internal ground of the device through ESD protection diodes. Because of that connection, the maximum differential voltage between the GND_S and GND_F pins must be kept below 200mV to prevent these dioes from unintentionally turning on.



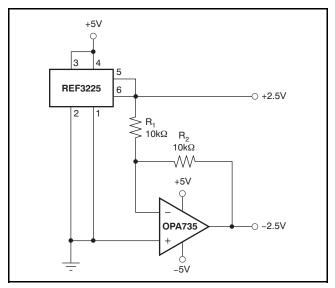
APPLICATION CIRCUITS

NEGATIVE REFERENCE VOLTAGE

For applications requiring a negative and positive reference voltage, the REF32xx and OPA735 can be used to provide a dual-supply reference from a ± 5 V supply. Figure 25 shows the REF3225 used to provide a ± 2.5 V supply reference voltage. The low drift performance of the REF32xx complements the low offset voltage and zero drift of the OPA735 to provide an accurate solution for split-supply applications. Care must be taken to match the temperature coefficients of R₁ and R₂.

DATA ACQUISITION

Data acquisition systems often require stable voltage references to maintain accuracy. The REF32xx family features stability and a wide range of voltages suitable for most microcontrollers and data converters. Figure 26, Figure 27, and Figure 28 show basic data acquisition systems.



NOTE:: Bypass capacitor is not shown.

Figure 25. REF3225 Combined with OPA735 to Create Positive and Negative Reference Voltages

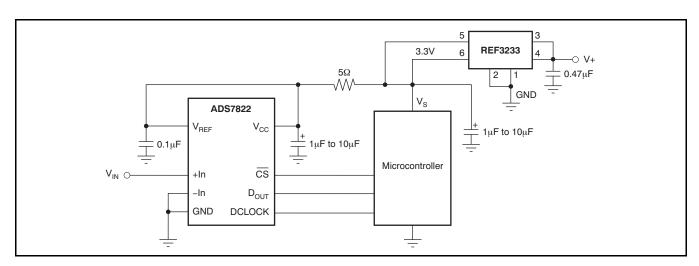


Figure 26. Basic Data Acquisition System 1

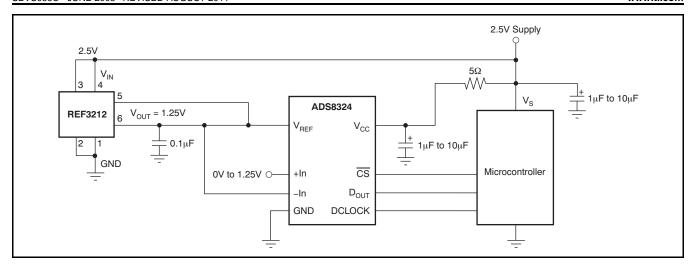


Figure 27. Basic Data Acquisition System 2

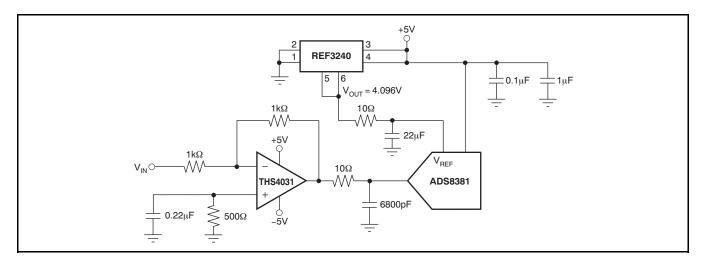


Figure 28. REF3240 Provides an Accurate Reference for Driving the ADS8381





REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

CI	nanges from Revision B (February 2006) to Revision C	Page
•	Added Pin Descriptions table	2
•	Added note to Enable/Shutdown parameter	4
•	Changed the minimum voltage for Enable/Shutdown with reference active from (0.75 × V _{IN}) to 1.5	4
•	Changed Current test condition from from (0.75 × V _{IN}) to (1.5V)	4
•	Added text, two tables, and one figure to Supply Voltage section	8
•	Changed pin 3 in Figure 24 from SHDN to ENABLE (typo)	10
•	Added paragraph to Load Regulation section	10

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
REF3212AIDBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32A
REF3212AIDBVR.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32A
REF3212AIDBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32A
REF3212AIDBVT.B	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32A
REF3212AIDBVT1G4	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32A
REF3212AIDBVT1G4.B	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32A
REF3220AIDBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32B
REF3220AIDBVR.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32B
REF3220AIDBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32B
REF3220AIDBVT.B	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32B
REF3220AIDBVT1G4	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32B
REF3220AIDBVT1G4.B	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32B
REF3225AIDBVR	NRND	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32C
REF3225AIDBVR.B	NRND	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32C
REF3225AIDBVT	NRND	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32C
REF3225AIDBVT.B	NRND	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32C
REF3230AIDBVR	NRND	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32D
REF3230AIDBVR.B	NRND	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32D
REF3230AIDBVT	NRND	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32D
REF3230AIDBVT.B	NRND	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32D
REF3233AIDBVR	NRND	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32E
REF3233AIDBVR.B	NRND	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32E
REF3233AIDBVT	NRND	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32E
REF3233AIDBVT.B	NRND	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32E
REF3240AIDBVR	NRND	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32F
REF3240AIDBVR.B	NRND	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32F
REF3240AIDBVT	NRND	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32F
REF3240AIDBVT.B	NRND	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	R32F

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- (1) Status: For more details on status, see our product life cycle.
- (2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.
- (3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.
- (4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF REF3212, REF3220, REF3225, REF3230, REF3240:

Enhanced Product: REF3212-EP, REF3220-EP, REF3225-EP, REF3230-EP, REF3240-EP

NOTE: Qualified Version Definitions:

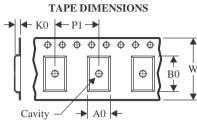
Enhanced Product - Supports Defense, Aerospace and Medical Applications



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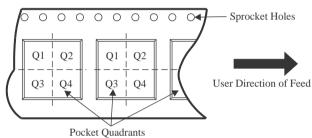
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

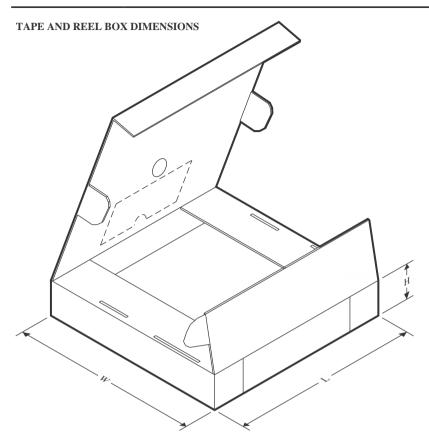


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
REF3212AIDBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
REF3212AIDBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
REF3212AIDBVT1G4	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
REF3220AIDBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
REF3220AIDBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
REF3220AIDBVT1G4	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
REF3225AIDBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
REF3225AIDBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
REF3230AIDBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
REF3230AIDBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
REF3233AIDBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
REF3233AIDBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
REF3240AIDBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
REF3240AIDBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3



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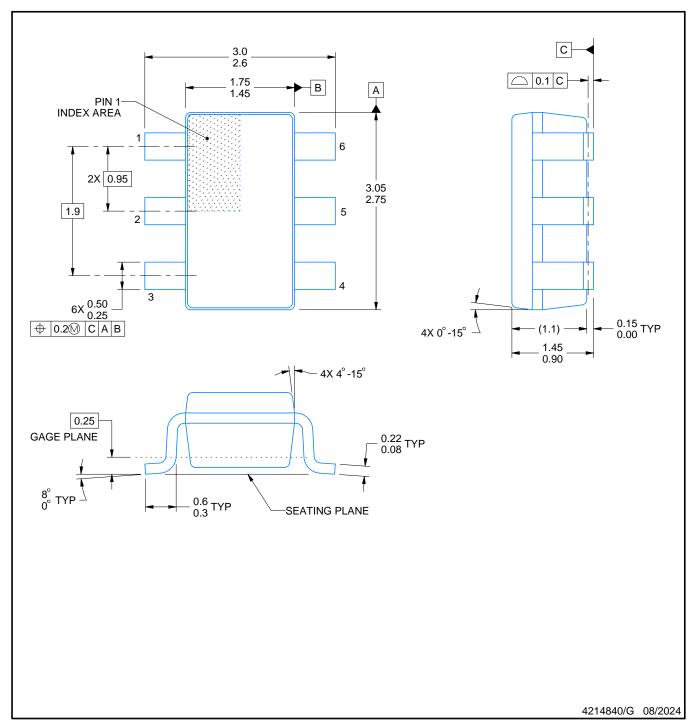


*All dimensions are nominal

An unrensions are normal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
REF3212AIDBVR	SOT-23	DBV	6	3000	445.0	220.0	345.0
REF3212AIDBVT	SOT-23	DBV	6	250	445.0	220.0	345.0
REF3212AIDBVT1G4	SOT-23	DBV	6	250	445.0	220.0	345.0
REF3220AIDBVR	SOT-23	DBV	6	3000	445.0	220.0	345.0
REF3220AIDBVT	SOT-23	DBV	6	250	445.0	220.0	345.0
REF3220AIDBVT1G4	SOT-23	DBV	6	250	445.0	220.0	345.0
REF3225AIDBVR	SOT-23	DBV	6	3000	445.0	220.0	345.0
REF3225AIDBVT	SOT-23	DBV	6	250	445.0	220.0	345.0
REF3230AIDBVR	SOT-23	DBV	6	3000	445.0	220.0	345.0
REF3230AIDBVT	SOT-23	DBV	6	250	445.0	220.0	345.0
REF3233AIDBVR	SOT-23	DBV	6	3000	445.0	220.0	345.0
REF3233AIDBVT	SOT-23	DBV	6	250	445.0	220.0	345.0
REF3240AIDBVR	SOT-23	DBV	6	3000	445.0	220.0	345.0
REF3240AIDBVT	SOT-23	DBV	6	250	445.0	220.0	345.0



SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

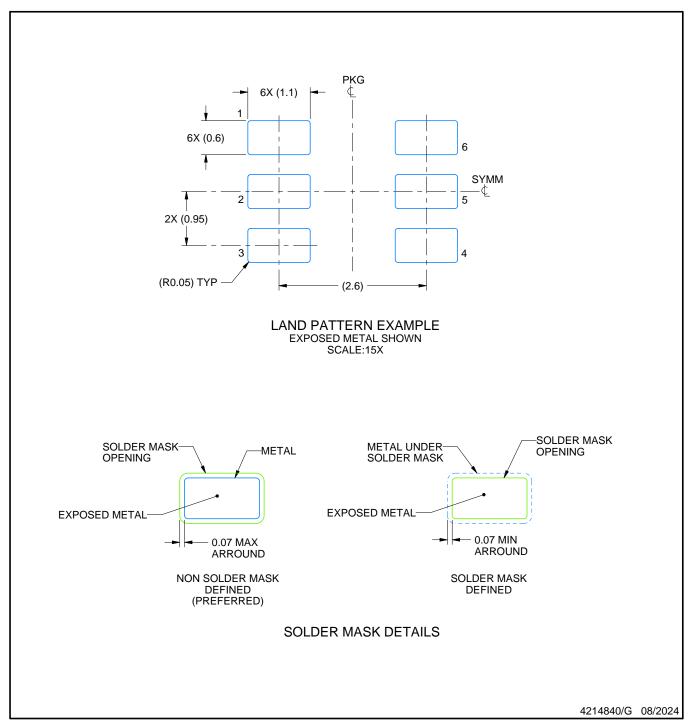
 2. This drawing is subject to change without notice.

 3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.

- 4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- 5. Refernce JEDEC MO-178.



SMALL OUTLINE TRANSISTOR



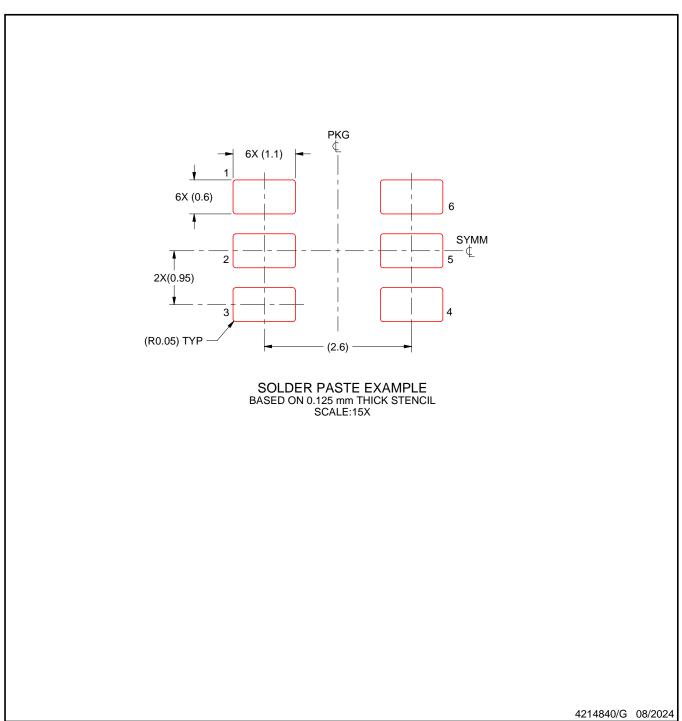
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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